



YOUSHANG SEMICONDUCTOR

**设计研发新型功率器件**

**各类小信号开关**

**中低压及高压大电流等场效应管**

0755-83047638

ysbdt@szyoushang.cn

www.szyoushang.cn



企业微信二维码



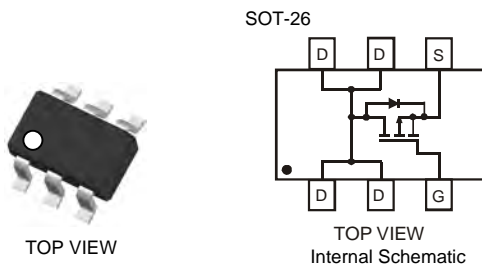
企业QQ二维码

## Features

- Low  $R_{DS(ON)}$ :
  - 80 m $\Omega$  @  $V_{GS} = -4.5V$
  - 110 m $\Omega$  @  $V_{GS} = -2.7V$
  - 130 m $\Omega$  @  $V_{GS} = -2.5V$
- Low Input/Output Leakage

## Mechanical Data

- Case: SOT-26
- Case Material – Molded Plastic. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish - Matte Tin Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 2
- Ordering Information: See page 2
- Weight: 0.008 grams (approximate)



## Maximum Ratings @ $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	-20	V
Gate-Source Voltage	$V_{GSS}$	$\pm 12$	V
Drain Current (Note 1) Continuous	$I_D$	$T_A = 25^\circ C$ -3.4 $T_A = 70^\circ C$ -2.7	A
Pulsed Drain Current (Note 2)	$I_{DM}$	-12	A
Body-Diode Continuous Current (Note 1)	$I_S$	2.0	A

## Thermal Characteristics

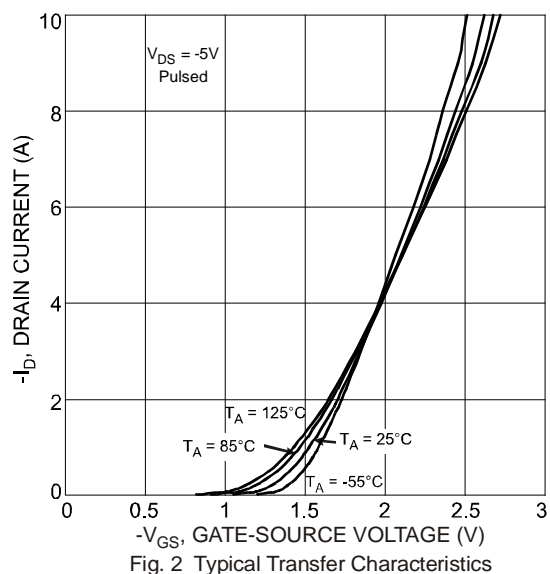
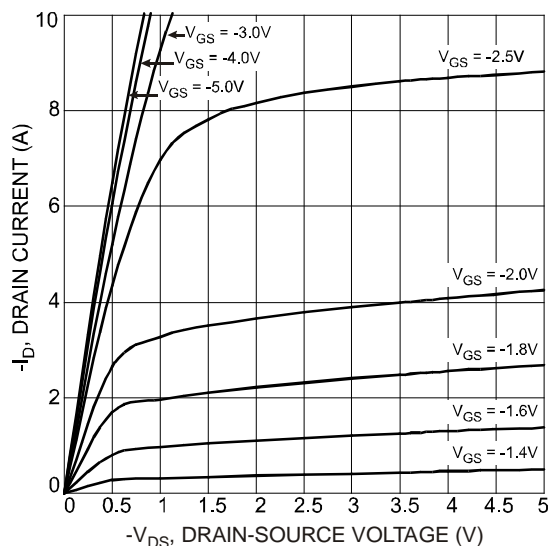
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	$P_D$	1.25	W
Thermal Resistance, Junction to Ambient (Note 1); Steady-State	$R_{\theta JA}$	100	$^\circ C/W$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ C$

- Notes:
1. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width  $t \leq 10s$ .
  2. Repetitive Rating, pulse width limited by junction temperature.
  3. No purposefully added lead.

**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>STATIC PARAMETERS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	-20	—	—	V	$I_D = -250\mu\text{A}, V_{GS} = 0\text{V}$
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	-1	$\mu\text{A}$	$V_{DS} = -20\text{V}, V_{GS} = 0\text{V}$
Gate-Body Leakage Current	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{DS} = 0\text{V}, V_{GS} = \pm 12\text{V}$
Gate Threshold Voltage	$V_{GS(th)}$	-0.6	—	-1.25	V	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$
On State Drain Current (Note 5)	$I_D(ON)$	-15	—	—	A	$V_{GS} = -4.5\text{V}, V_{DS} = -5\text{V}$
Static Drain-Source On-Resistance (Note 5)	$R_{DS(ON)}$	—	51	80	m $\Omega$	$V_{GS} = -4.5\text{V}, I_D = -4.5\text{A}$
		—	82	110		$V_{GS} = -2.7\text{V}, I_D = -3.8\text{A}$
		—	94	130		$V_{GS} = -2.5\text{V}, I_D = -3.7\text{A}$
Forward Transconductance (Note 5)	$g_{FS}$	—	6.3	—	S	$V_{DS} = -10\text{V}, I_D = -4.5\text{A}$
Diode Forward Voltage (Note 5)	$V_{SD}$	—	0.79	-1.26	V	$I_S = -1.7\text{A}, V_{GS} = 0\text{V}$
Maximum Body-Diode Continuous Current (Note 1)	$I_S$	—	—	1.7	A	—
<b>DYNAMIC PARAMETERS (Note 6)</b>						
Total Gate Charge	$Q_g$	—	7.3	—	nC	$V_{GS} = -4.5\text{V}, V_{DS} = -10\text{V}, I_D = 4.5\text{A}$
Gate-Source Charge	$Q_{gs}$	—	2.0	—	nC	$V_{GS} = -4.5\text{V}, V_{DS} = -10\text{V}, I_D = 4.5\text{A}$
Gate-Drain Charge	$Q_{gd}$	—	1.9	—	nC	$V_{GS} = -4.5\text{V}, V_{DS} = -10\text{V}, I_D = 4.5\text{A}$
Turn-On Delay Time	$t_{D(on)}$	—	12	—	ns	$V_{DS} = -10\text{V}, V_{GS} = -4.5\text{V},$ $R_L = 10\Omega, R_G = 6\Omega$
Turn-On Rise Time	$t_r$	—	20	—	ns	
Turn-Off Delay Time	$t_{D(off)}$	—	38	—	ns	
Turn-Off Fall Time	$t_f$	—	41	—	ns	
Input Capacitance	$C_{iss}$	—	443	—	pF	$V_{DS} = -16\text{V}, V_{GS} = 0\text{V}$ $f = 1.0\text{MHz}$
Output Capacitance	$C_{oss}$	—	125	—	pF	
Reverse Transfer Capacitance	$C_{rss}$	—	98	—	pF	

Notes: 5. Test pulse width  $t = 300\mu\text{s}$ .  
 6. Guaranteed by design. Not subject to production testing.



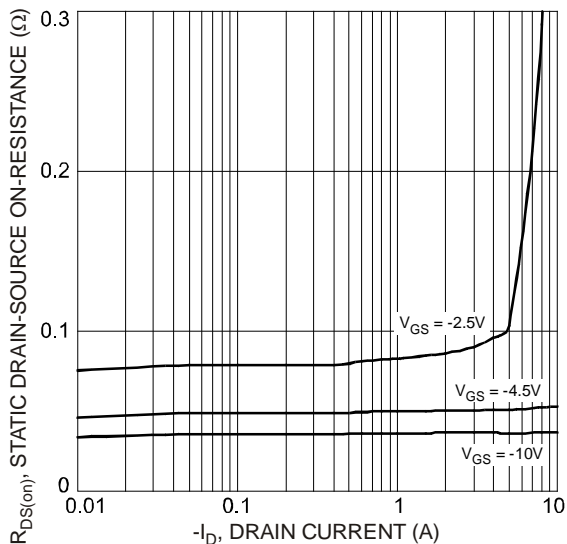


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

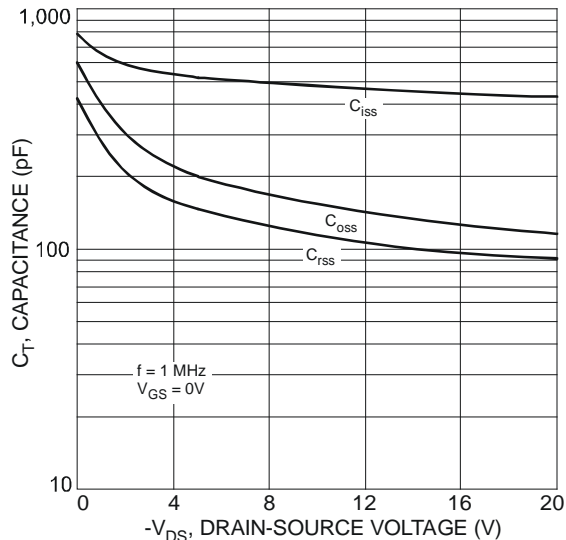


Fig. 4 Typical Total Capacitance

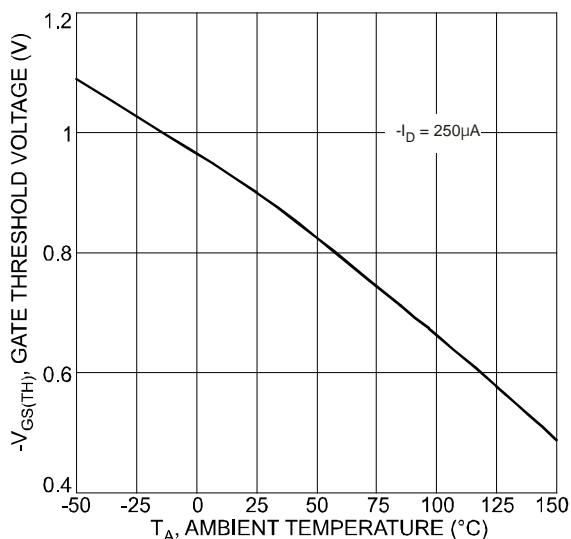


Fig. 5 Gate Threshold Voltage vs. Ambient Temperature

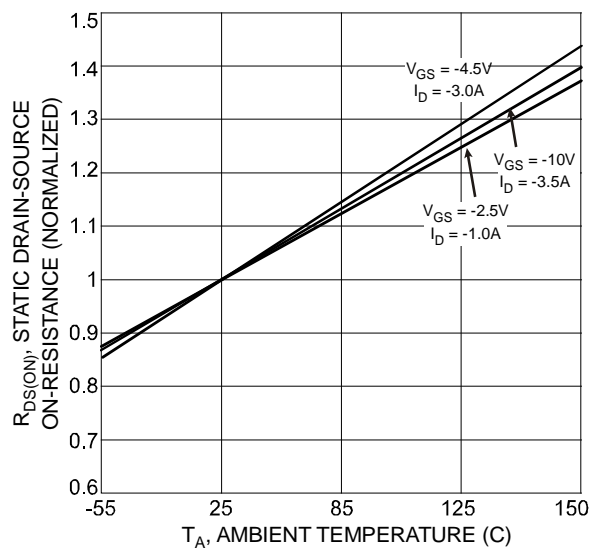


Fig. 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

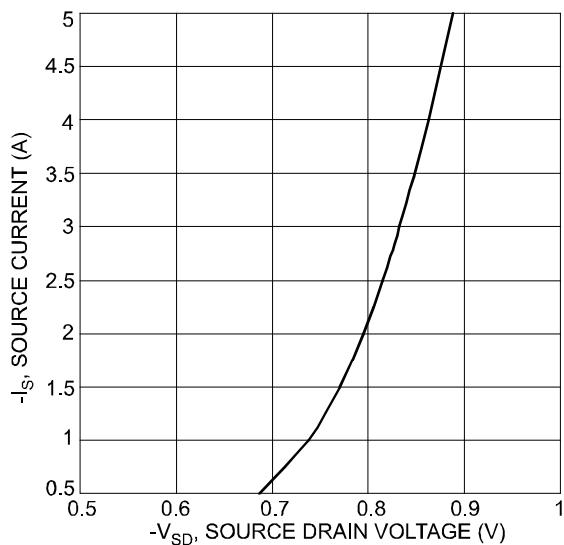
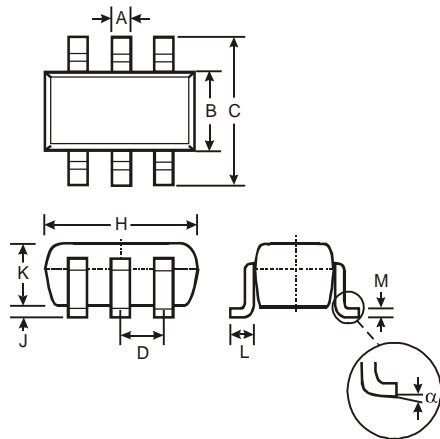


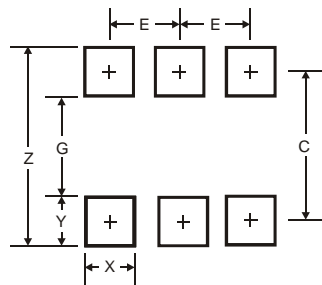
Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

**Package Outline Dimensions**



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
$\alpha$	0°	8°	—
All Dimensions in mm			

**Suggested Pad Layout**



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C	2.40
E	0.95